

RJP65T54DPM-A0

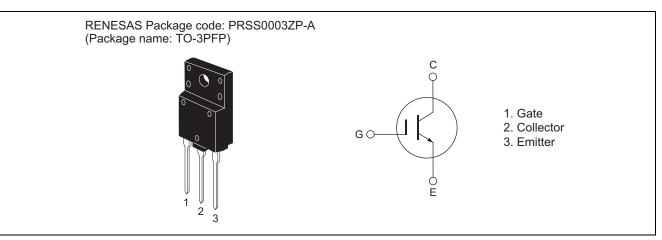
650V - 30A - IGBT Application: Partial switching circuit R07DS1365EJ0110 Rev.1.10 Dec 19, 2016

Data Sheet

Features

- Low collector to emitter saturation voltage $V_{1} = 1.25 V \text{ tr} (ct I_{1} = 20 \text{ A} V_{2} = 15)$
- $V_{CE(sat)} = 1.35 \text{ V typ.}$ (at $I_C = 30 \text{ A}$, $V_{GE} = 15 \text{ V}$, $Ta = 25^{\circ}C$)
- Isolated package
- Trench gate and thin wafer technology (G7H series)
- High speed switching
- Operation frequency $(50Hz \le f < 20kHz)$
- Not guarantee short circuit withstand time

Outline



Absolute Maximum Ratings

				$(Tc = 25^{\circ}C)$
ltem		Symbol	Ratings	Unit
Collector to emitter voltage		VCES	650	V
Gate to emitter voltage		VGES	±30	V
Collector current	Tc = 25 °C	lc	60	A
	Tc = 100 °C	lc	30	A
Collector peak current		ic(peak) Note1	225	A
Collector dissipation		Pc	63.5	W
Junction to case thermal resistance		өј-с	2.35	°C/W
Junction temperature		Tj ^{Note2}	175	°C
Storage temperature		Tstg	-55 to +150	°C

Note: Continuous heavy condition (e.g. high temperature/voltage/current or high variation of temperature) may affect a reliability even if it are within the absolute maximum ratings. Please consider derating condition for appropriate reliability in reference Renesas Semiconductor Reliability Handbook (Recommendation for Handling and Usage of Semiconductor Devices) and individual reliability data.

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Electrical Characteristics

						$(Ta = 25^{\circ}C)$	
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current	I _{CES}		_	10	μΑ	$V_{CE} = 650 \text{ V}, \text{ V}_{GE} = 0$	
Gate to emitter leak current	I _{GES}		_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	5	—	7	V	$V_{CE} = 10V, I_{C} = 1.0 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.35	1.68	V	Ic = 30 A, V _{GE} = 15V ^{Note3}	
Total gate charge	Qg		72		nC	V _{CE} = 400 V V _{GE} = 15V	
Gate to emitter charge	Qge		10		nC		
Gate to collector charge	Qgc		30		nC	Ic= 30A	
Input capacitance	Cies	_	1400	_	pF	V _{CE} = 25 V V _{GE} = 0 f = 1 MHz	
Output capacitance	Coes		42	_	pF		
Reveres transfer capacitance	Cres		30	_	pF		
Turn-on delay time	t _{d(on)}		35		ns	$V_{CC} = 400 V$ $V_{GE} = 15 V$, $I_C = 30 A$ $Rg = 10 \Omega$, $T_C = 25 °C$	
Rise time	tr		20	_	ns		
Turn-off delay time	t _{d(off)}	_	120	_	ns		
Fall time	tr	_	130	_	ns	Inductive load ^{Note4}	
Turn-on loss energy	Eon	_	0.33	—	mJ		
Turn-off loss energy	Eoff	_	0.76	—	mJ		
Turn-on delay time	t _{d(on)}		31		ns	$V_{CC} = 400 V V_{GE} = 15 V, I_{C} = 30 A Rg = 10 \Omega, T_{C} = 150^{\circ}C$	
Rise time	tr		22	_	ns		
Turn-off delay time	t _{d(off)}	_	128	_	ns		
Fall time	tr	_	156	_	ns	Inductive load Note4	
Turn-on loss energy	Eon	_	0.47	—	mJ		
Turn-off loss energy	Eoff	_	1.04	—	mJ		

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

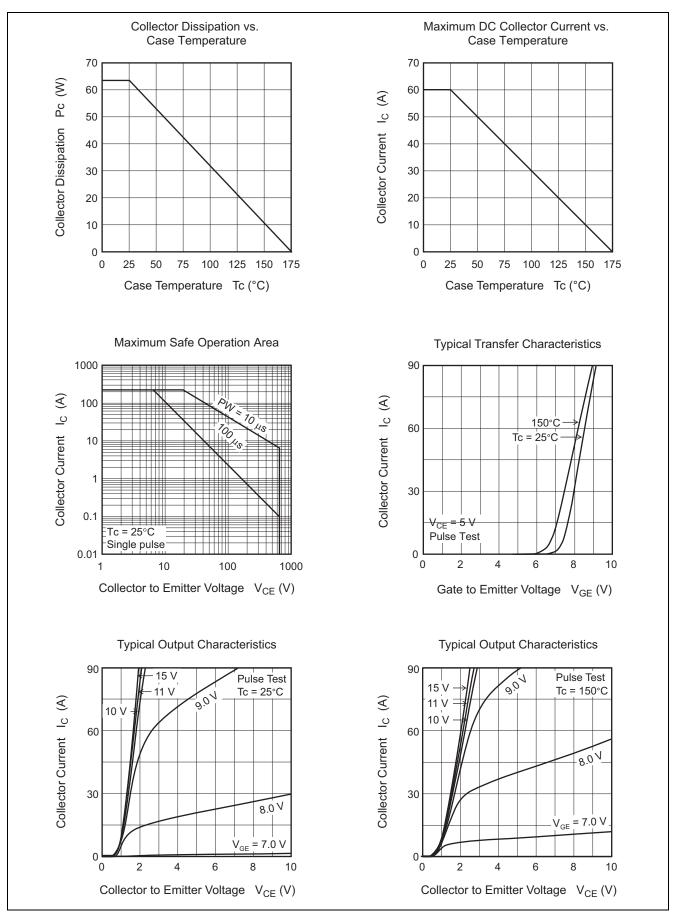
 Please use this device in the thermal conditions which the junction temperature does not exceed 175°C. Renesas IGBT Application Note is disclosed about reliability test and application condition up to 175°C.

3. Pulse test

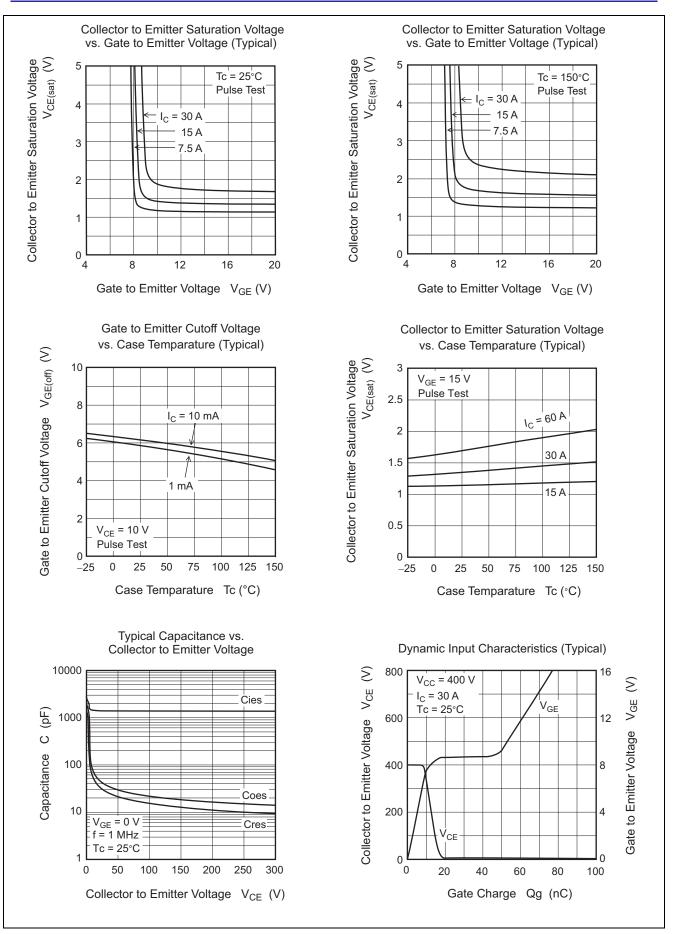
4. Switching time test circuit and waveform are shown below.

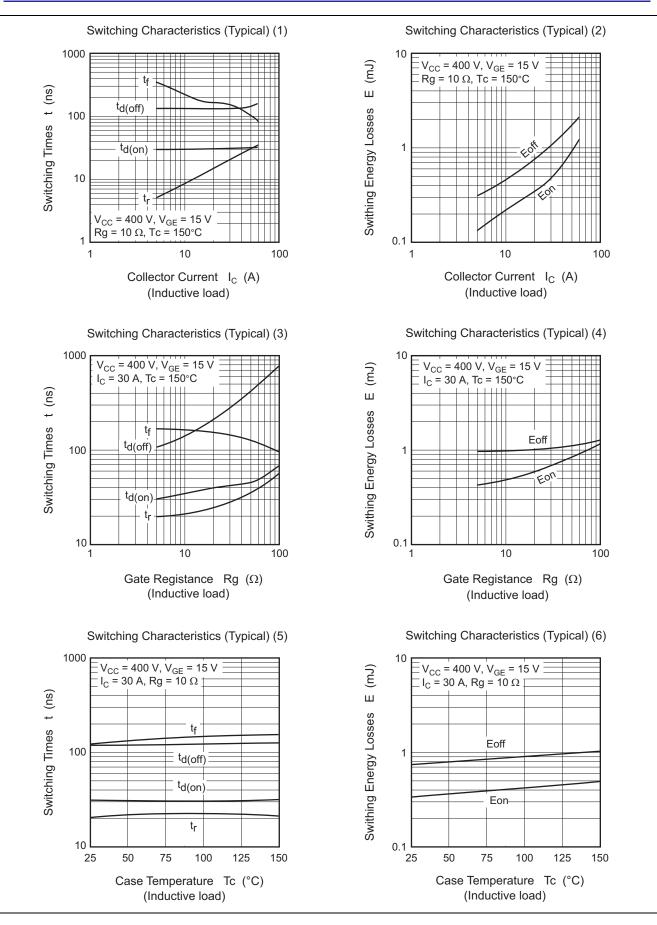


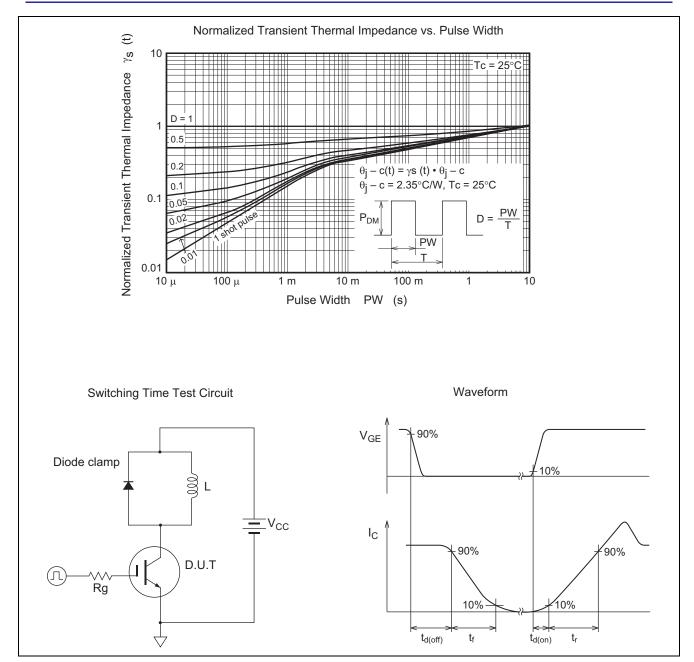
Main Characteristics





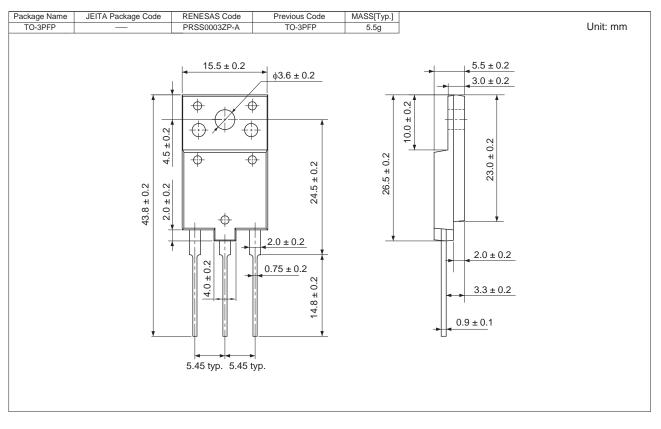








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container	
RJP65T54DPM-A0#T2	1000 pcs	Box (Tube)	



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